

Product Summary

BV _{DSS}	Rds(on)	Ι _D T _C = +25°C
100V	57mΩ @ V _{GS} = 10V	20A
	71mΩ @ V _{GS} = 6V	18A
	96mΩ @ V _{GS} = 4.5V	16A

Description and Applications

This new generation N-Channel Enhancement Mode MOSFET is designed to minimize R_{DS(ON)} yet maintain superior switching performance. This device is ideal for use in notebook battery power management and load switches.

- DC-DC converters
- Load switches

PowerDI5060-8 (SWP) (Type UX)



Top View

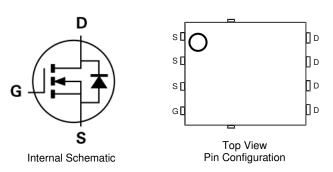
Bottom View



- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On State Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts gualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: PowerDI[®]5060-8 •
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish-Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

Orderable Part Number		Baakaga	Packing		
	Orderable Part Number	Package	Quantity	Carrier	
	DMTH10H072LPS-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Tape & Reel	
Notes: 1. EU Directive 2002/95/EC (BoHS), 2011/65/EU (BoHS 2) & 2015/863/EU (BoHS 3) compliant. All applicable BoHS exemptions applied.					

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



) | | = Manufacturer's Marking TH1H72LS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)



Maximum Ratings (@T_C = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	100	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current, V_{GS} = 10V (Note 7)	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	ID	20 14	A
Maximum Continuous Body Diode Forward Current (Note 7)			Is	20	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			IDM	80	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			I _{SM}	80	A
Avalanche Current, L = 0.1mH (Note 8)			I _{AS}	6	А
Avalanche Energy, L = 0.1mH (Note 8)			E _{AS}	1.8	mJ

Thermal Characteristics (@T_C = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	98	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	3.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	49	°C/W
Total Power Dissipation (Note 7)	T _C = +25°C	PD	51.7	W
Thermal Resistance, Junction to Case (Note 7)		R _θ JC	2.9	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_C = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)	0,		- 76		•		
Drain-Source Breakdown Voltage	BV _{DSS}	100		—	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_		1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}			±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)	-					-	
Gate Threshold Voltage	V _{GS(TH)}	1	—	3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		_	44	57		$V_{GS} = 10V, I_D = 4.5A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		54	71	mΩ	$V_{GS} = 6V, I_D = 4A$	
	· · ·		73	96		$V_{GS} = 4.5V, I_D = 2.6A$	
Diode Forward Voltage	V _{SD}		0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	266	—		V_{DS} = 50V, V_{GS} = 0V, f = 1MHz	
Output Capacitance	C _{oss}		87.2	_	pF		
Reverse Transfer Capacitance	Crss	_	3.6	_			
Gate Resistance	Rg	_	7.0	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qq		2.8	_			
Total Gate Charge (V _{GS} = 10V)	Qg	_	5.1	_	nC	$V_{DS}=50V,\ I_D=4.5A$	
Gate-Source Charge	Q _{gs}	_	0.8	_	nc		
Gate-Drain Charge	Q _{gd}		1.7	_			
Turn-On Delay Time	t _{D(ON)}		3.0	_			
Turn-On Rise Time	t _R		2.8	_		$V_{DD} = 50V, V_{GS} = 10V,$ $I_D = 4.5A, R_G = 3\Omega$	
Turn-Off Delay Time	t _{D(OFF)}		9.5	_	ns		
Turn-Off Fall Time	t _F	_	3.2	_			
Body Diode Reverse Recovery Time	t _{RR}	_	37.5	_	ns		
Body Diode Reverse Recovery Charge	Q _{RR}		86.8	_	nC	I _S = 4.5A, di/dt = 300A/μs	

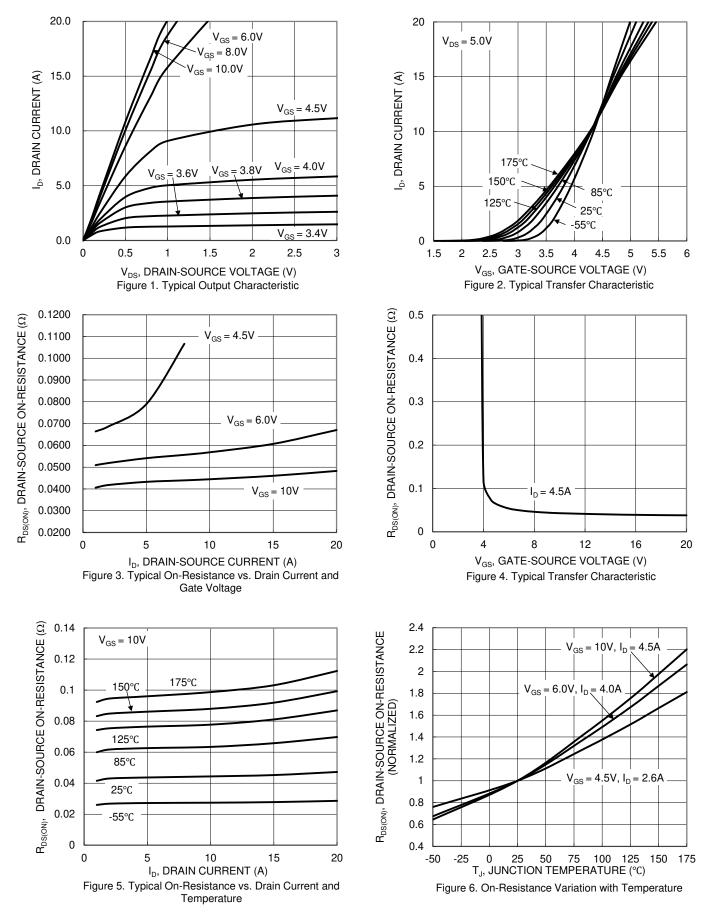
Notes:

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).
8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
9. Short duration pulse test used to minimize self-heating effect.
10. Curventend but desize.

10. Guaranteed by design. Not subject to product testing.

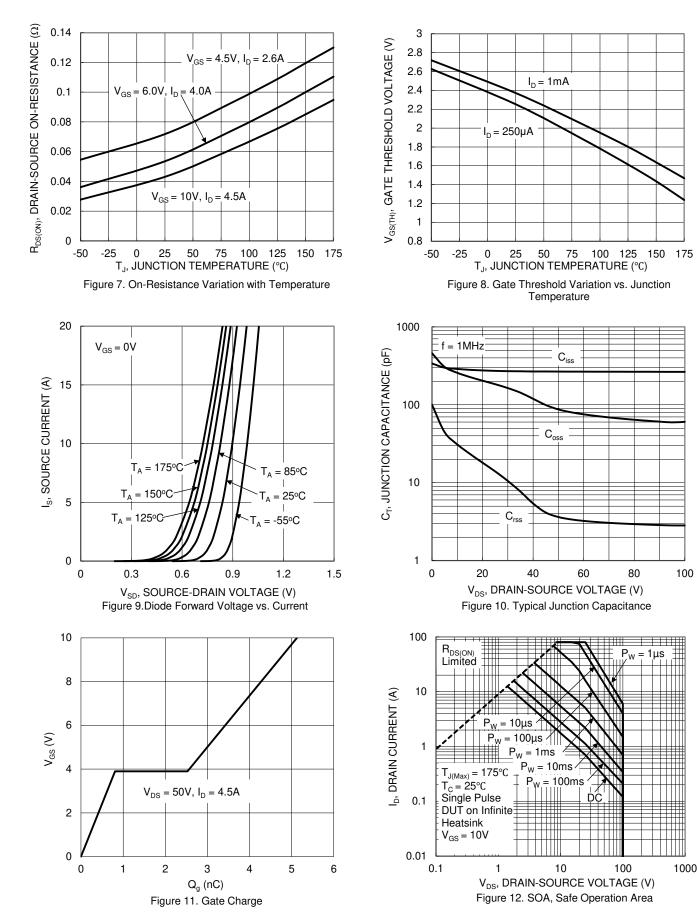


DMTH10H072LPS



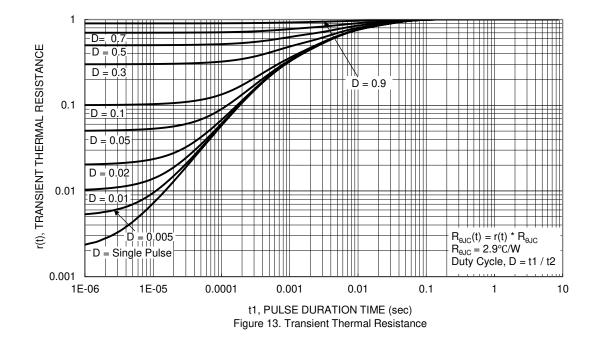
DMTH10H072LPS Document number: DS39699 Rev. 4 - 2





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PowerDI5060-8 (SWP) (Type UX) Min

0.90

0

0.30

0.20

4.70

3.56

3.78

3.46

1.05

3.205

10°

6°

Max

1.10

0.05

0.50

0.35

0.25REF 0.230 0.330 0.277

5.15 BS

5.10

3.96

4.18

6.40 BS

3.86

1.27BSC

0.050REF

4.005

12°

8°

5.60 6.00

4.195 4.595

0.635 0.835

0.635 0.835

0.200 0.400

0.025 0.225

All Dimensions in mm

Тур

1.00

0.41

0.25

4.90

3.76

3.98

5.80

3.66

4.395

0.735

0.735

0.300

0.125

3.605

11°

7°

Dim

Α

A1

b

b2

b4

С

D

D1

D2

D2a

Ε

E1

E2

E2a

е

k

L

La

L1

L1a

L4

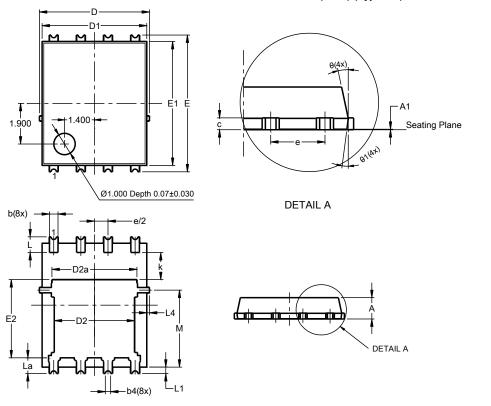
Μ

θ

θ1

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



PowerDI5060-8 (SWP) (Type UX)

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

ſ		
Y3	Y2 Y2 Y2 Y2 Y2 Y2 Y2 Y2 Y2 Y2 Y2 Y2 Y2 Y	
		G1 Y(4x)

PowerDI5060-8(SWP) (Type UX)

Dimensions	Value			
-	(in mm)			
С	1.270			
G	0.660			
G1	0.820			
Х	0.610			
X1	4.100			
X2	5.190			
X3	4.420			
Y	1.270			
Y1	1.020			
Y2	3.810			
Y3	6.610			



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